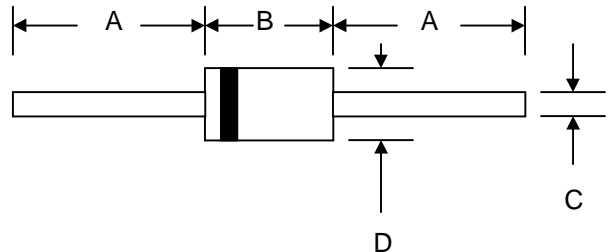


Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.34 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version**



DO-41		
Dim	Min	Max
A	24.5	—
B	4.06	5.21
C	0.60	0.80
D	2.00	3.00
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	BA157	BA158	BA159	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	400	600	1000	V
Working Peak Reverse Voltage	V _{RWM}				
DC Blocking Voltage	V _R				
RMS Reverse Voltage	V _{R(RMS)}	280	420	700	V
Average Rectified Output Current (Note 1) @T _A = 75°C	I _O	1.0			A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	30			A
Forward Voltage @I _F = 1.0A	V _{FM}	1.2			V
Peak Reverse Current @T _A = 25°C	I _{RM}	5.0			μA
At Rated DC Blocking Voltage @T _A = 100°C		100			
Reverse Recovery Time (Note 2)	t _{rr}	150	250	500	nS
Typical Junction Capacitance (Note 3)	C _j	15			pF
Operating Temperature Range	T _j	-65 to +150			°C
Storage Temperature Range	T _{STG}	-65 to +150			°C

***Glass passivated forms are available upon request**

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case
2. Measured with I_F = 0.5A, I_R = 1.0A, IRR = 0.25A. See figure 5.
3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

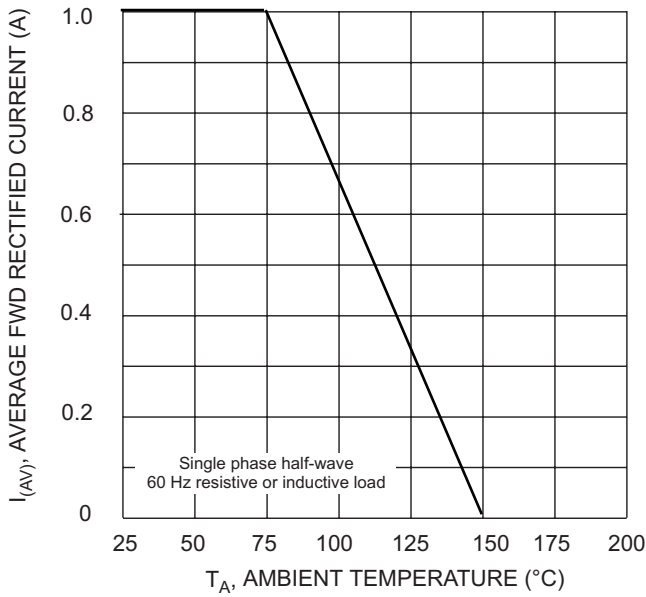


Fig. 1 Forward Derating Curve

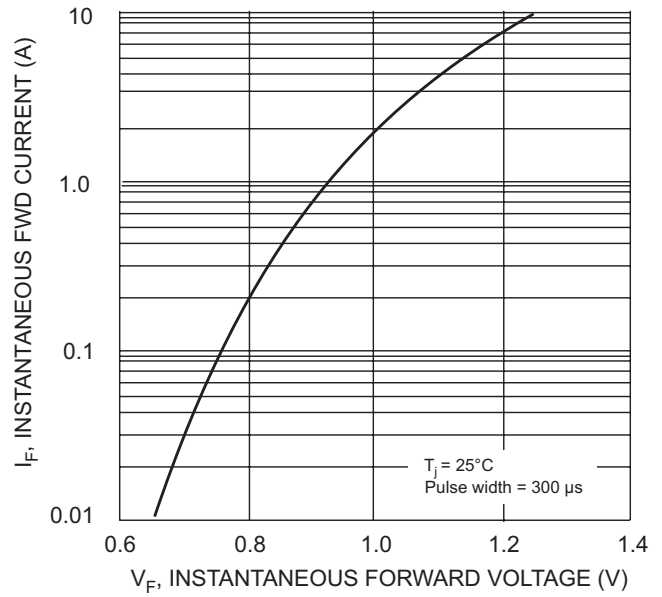


Fig. 2 Typical Forward Characteristics

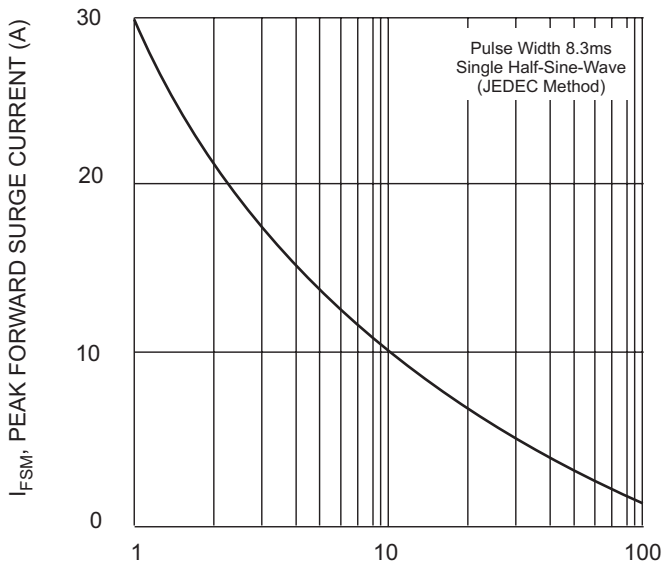


Fig. 3 Peak Forward Surge Current

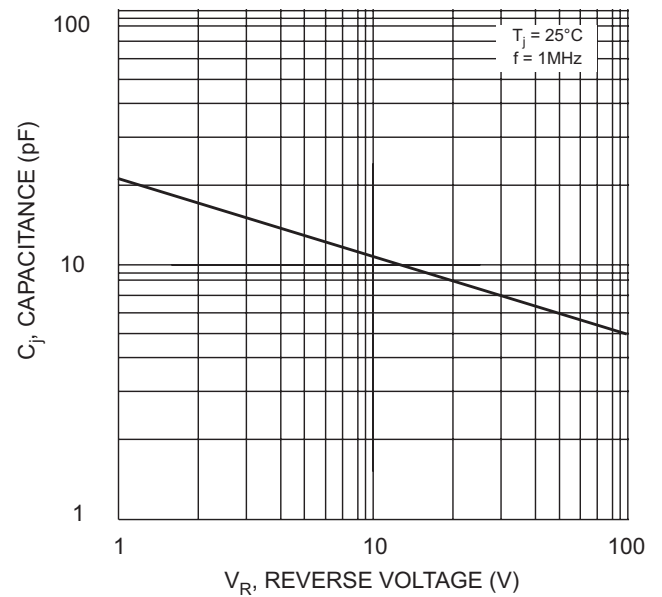
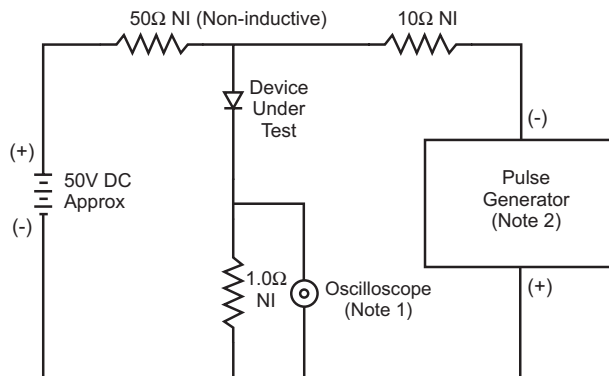
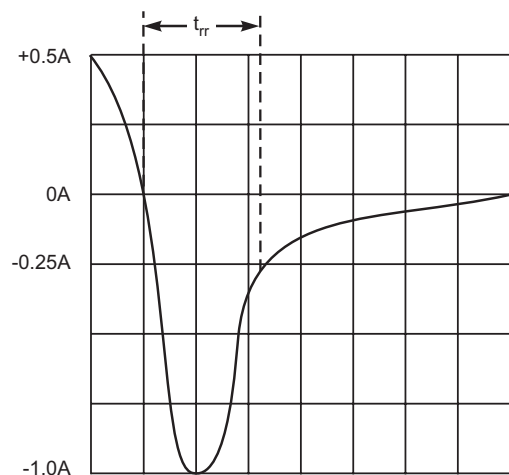


Fig. 4 Typical Junction Capacitance



Notes:

1. Rise Time = 7.0ns max. Input Impedance = 1.0M Ω , 22pF.
2. Rise Time = 10ns max. Input Impedance = 50 Ω .



Set time base for 5/10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit